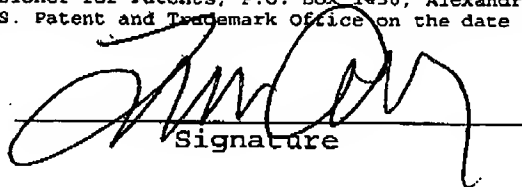
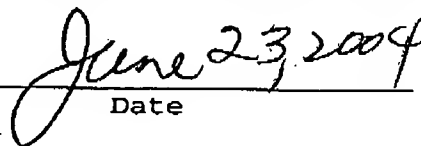


Docket No.: L&amp;L-I0178

CERTIFICATION OF MAILING OR TRANSMISSION

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Applic. No. : 09/996,279 Confirmation No.: 4049  
Inventor : Lothar Risch et al.  
Filed : November 28, 2001  
Title : Double Gate MOSFET Transistor and Method  
for the Production Thereof  
TC/A.U. : 2814  
Examiner : Shrinivas H. Rao  
Customer No. : 24131

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S i r :

Responsive to the final Office Action dated March 26, 2004,  
kindly amend the above-identified application as follows:

Amendments to the Claims are reflected in the listing of  
claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 9 of this paper.